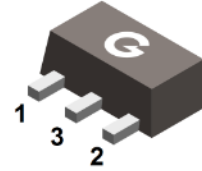
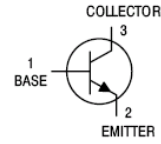


Features

- High BV_{CEO}
- High DC current gain
- Epitaxial planar die construction
- Complimentary to T2SA1201
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF



SOT-89

Mechanical Data

- Case: SOT-89
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
T2SC2881-O	SOT-89	1000 pcs / Tape & Reel	CO1
T2SC2881-Y	SOT-89	1000 pcs / Tape & Reel	CY1

Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Breakdown Voltage	V_{CBO}	120	V
Collector-Emitter Breakdown Voltage	V_{CEO}	120	V
Emitter-Base Breakdown Voltage	V_{EBO}	5	V
Continuous Collector Current	I_C	0.8	A
Peak Collector Current ($t_p \leq 1\text{ms}$)	I_{CM}	1.6	A
Continuous Base Current	I_B	0.16	A

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation ($T_A = 25^\circ\text{C}$)	P_D	0.5	W
Power Dissipation ($T_A = 25^\circ\text{C}$) *1		2	W
Thermal Resistance Junction-to-Air *1	$R_{\theta JA}$	60	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Case *1	$R_{\theta JC}$	25	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Lead *1	$R_{\theta JL}$	15	$^\circ\text{C/W}$
Operating junction Temperature	T_J	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note 1: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1\text{mA}, I_E = 0$	120	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}, I_B = 0$	120	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 1\text{mA}, I_C = 0$	5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = 120\text{V}, I_E = 0$	-	-	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 5\text{V}, I_C = 0$	-	-	0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = 5\text{V}, I_C = 100\text{mA}$	80	-	240	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$	-	-	1	V
Base-Emitter Voltage	$V_{BE(on)}$	$I_C = 500\text{mA}, V_{CE} = 5\text{V}$	-	-	1	V
Transition Frequency	f_T	$I_C = 100\text{mA}, V_{CE} = 5\text{V}$	-	120	-	MHz
Collector Output Capacitance	C_{OBO}	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	30	pF

Classification of h_{FE}

Rank	O	Y
Range	80-160	120-240

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

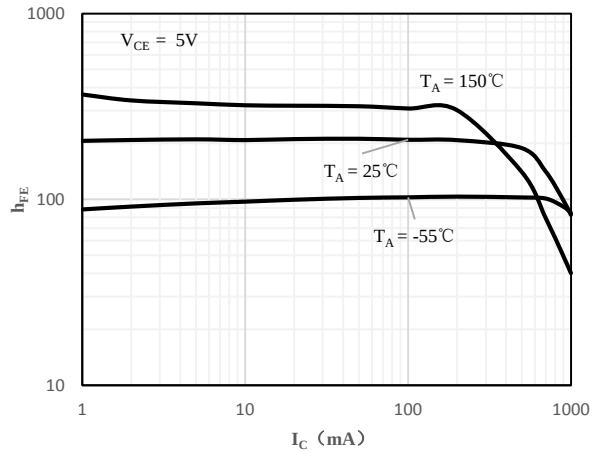


Fig 1 h_{FE} vs. I_C

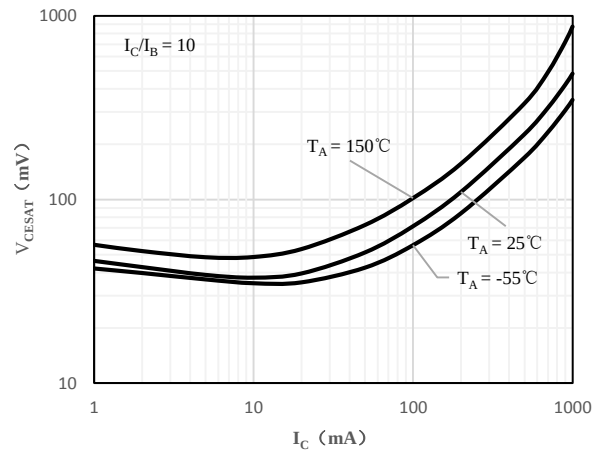


Fig 2 $V_{CE(sat)}$ vs. I_C

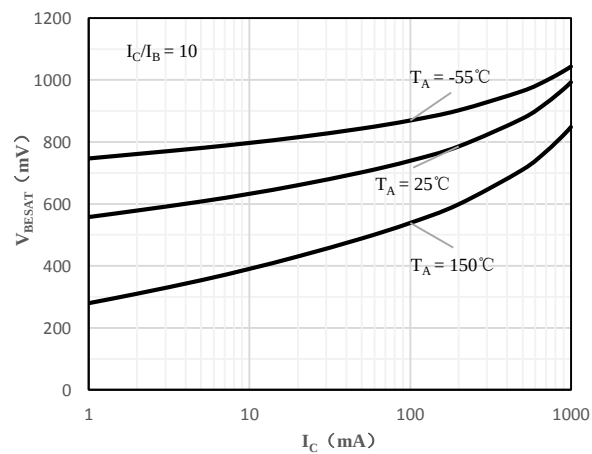


Fig 3 $V_{BE(sat)}$ vs. I_C

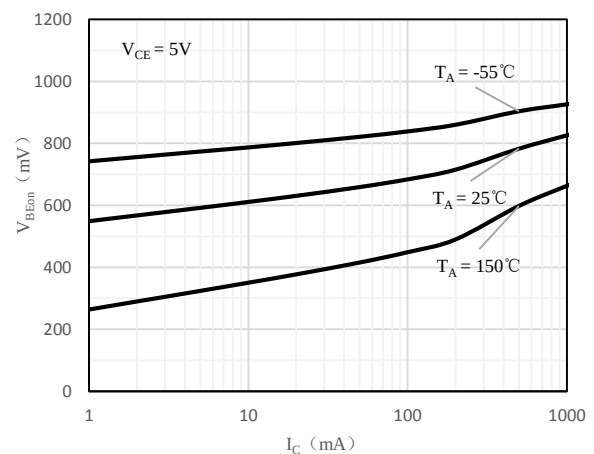


Fig 4 $V_{BE(on)}$ vs. I_C

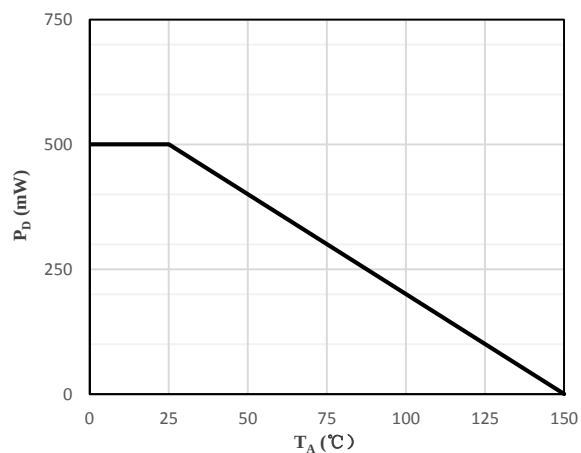
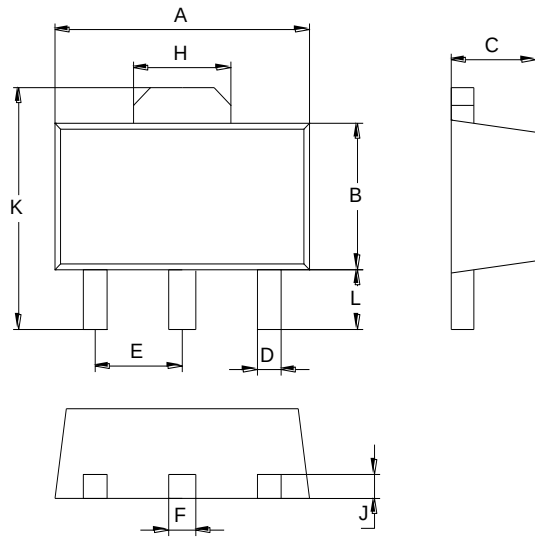


Fig 5 P_D vs. T_A

Package Outline Dimensions (Unit: mm)



SOT-89		
Dimension	Min.	Max.
A	4.30	4.70
B	2.25	2.65
C	1.30	1.70
D	0.30	0.50
E	1.40	1.60
F	0.38	0.58
H	1.60	1.80
J	0.30	0.50
L	0.90	1.10
K	3.95	4.35

Mounting Pad Layout (Unit: mm)

SOT-89

